

	<h2 style="color: #E67E22;">FQB50N06TM</h2>
	<p>Hersteller-Teilenummer: FQB50N06TM</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 50A D2PAK</p> <p>Datenblätter:  FQB50N06TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1114 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB50N06TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 50A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1114 pcs Stock
Hersteller Standard Vorlaufzeit	7 Weeks
detaillierte Beschreibung	N-Channel 60V 50A (Tc) 3.75W (Ta), 120W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 120W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	22 mOhm @ 25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	41nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1540pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB50N06TM-ND



















































FQB50N06TM ist neu im Original. Suche FQB50N06TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB50N06TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB50N06TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB50N06M VB FQB50N06M VB</p>	 <p>FQB52N25 FAIRCHILD FAIRCHILD TO-263</p>	 <p>FQB50N10 FAIRCHILD FAIRCHILD TO-263</p>	 <p>FQB55N06TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 55A D2PAK</p>
 <p>FQB50N06LTM Fairchild/ON Semiconductor MOSFET N-CH 60V 52.4A D2PAK</p>	 <p>FQB55N06TM Fairchild/ON Semiconductor MOSFET N-CH 60V 55A D2PAK</p>	 <p>FQB50N06LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 52.4A D2PAK</p>	 <p>FQB50N06L FSC FQB50N06L FSC</p>

heiße Teile

Mehr

 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM
 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM	 FQB4N50TM
 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM
 FQB4N90TM	 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06
 FQB50N06C	 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M
 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM	 FQB55N10
 FQB55N10TM	 FQB55N10TM	 FQB5N20L	 FQB5N30TM	 FQB5N30TM
 FQB5N50C	 FQB5N50CF	 FQB5N50CTM	 FQB5N50CTM	 FQB5N60CTM
 FQB5N60CTM	 FQB5N90TM	 FQB5N90TM	 FQB5P10TM	 FQB5P10TM
 FQB630TM	 FQB630TM	 FQB65N06	 FQB65N06TM	 FQB65N06TM

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